

规格书编号

SPEC NO : HDDB08NSSB11SP01

产品规格书

SPECIFICATION

CUSTOMER 客户: _____

PRODUCT 产品: _____ SAW DUPLEXER _____

MODEL NO 型号: _____ HDDB08NSS-B11 _____

MARKING 印字: _____ B079 _____

PREPARED 编制: _____ CHECKED 审核: _____

APPROVED 批准: _____ DATE 日期: _____ 2016-05-06 _____

客户确认 CUSTOMER RECEIVED:		
审核 CHECKED	批准 APPROVED	日期 DATE

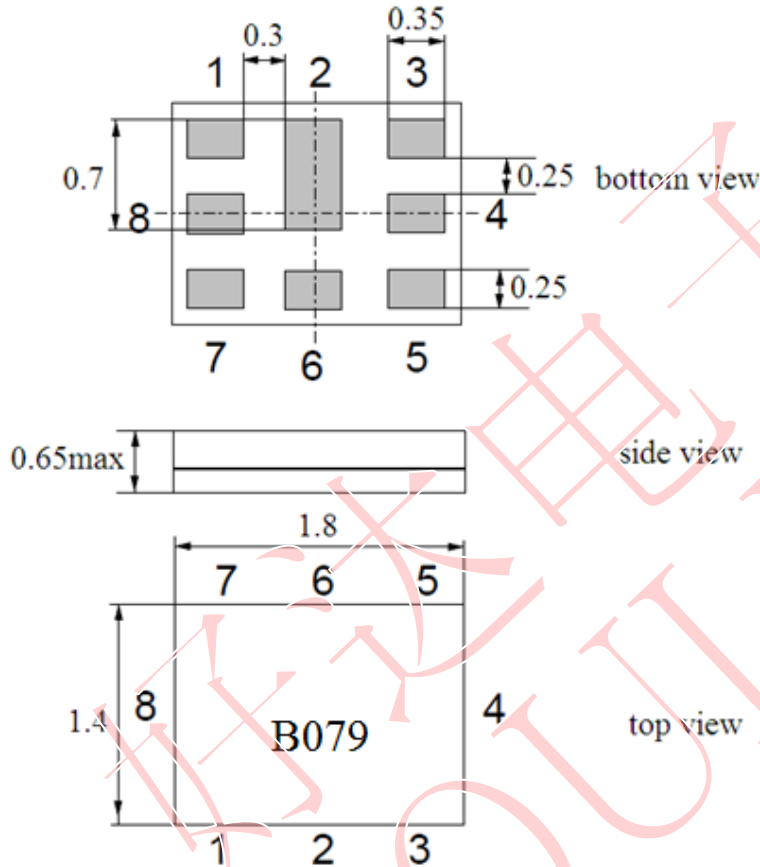
无锡市好达电子有限公司
Shoulder Electronics Limited

Factory Address: NO. 115, Gaoyun Road, Binhu Economic & Technology Development Area, Wuxi, Jiangsu, China. Tel: 86-510-85629111
Country of origin: China

1. Application

- Low-loss Saw duplexer for mobile telephone LTE and WCDMA Band8 systems.
- Low insertion attenuation and low passband ripple.
- Usable passband 35MHz
- High isolation between Tx and Rx.
- RoHS compatible

2. DIMENSION (PKG SIZE 1.8 x 1.4 x 0.6mm)

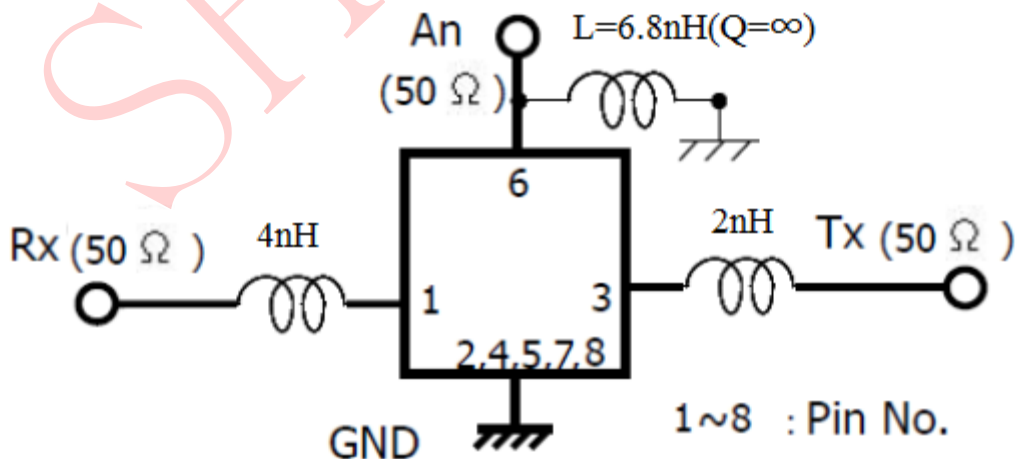


Marking: B079

Pin configuration

- 3. Tx Input
- 6. Antenna
- 1. Rx Output
- 2,4,5,7,8 To be grounded

3. TEST CIRCUIT



4. Maximum Rating

Items	Conditions
Operation temperature rang	-30℃ ~ +85℃
Storage temperature rang	-40℃ ~ +85℃
ESD voltage	ESD(MM) : 50VDC
Sensitive discharge device	ESD(HBM) : 175VDC
DC Voltage VDC	3V (25+/-2 deg.C)
Moisture Sensitivity Level	MSL 2

5. ELECTRICAL SPECIFICATION

Table1. Electrical Specification

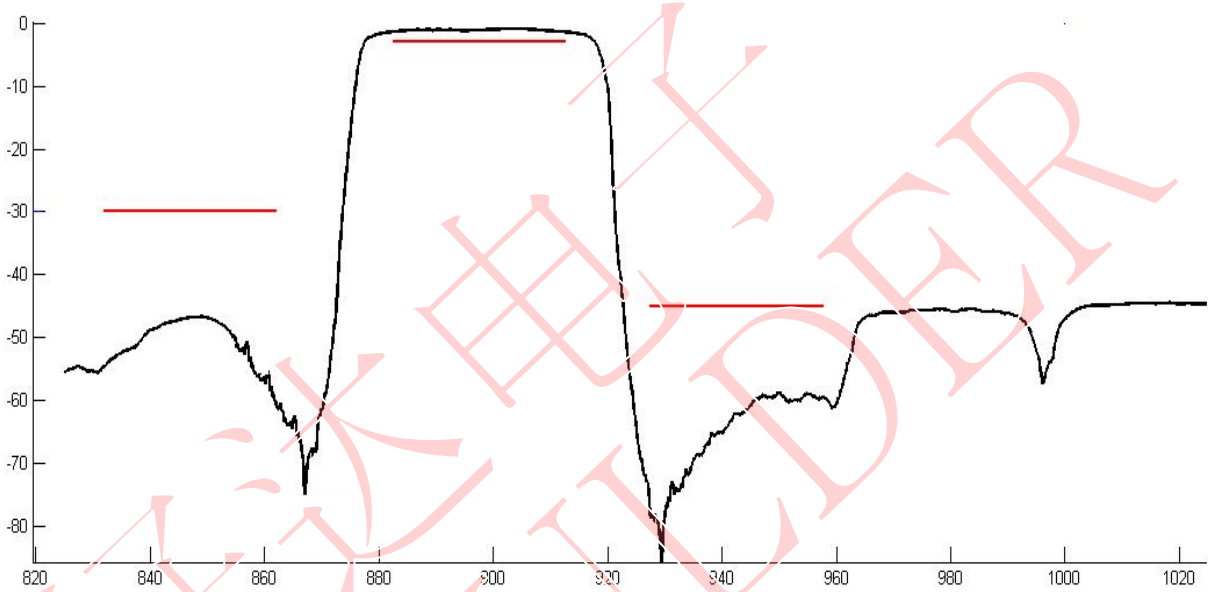
Item		Condition (MHz)	Specification			Unit	
			Min	Typ	Max		
	Insertion loss	882.4~912.6		1.7	3.0	dB	
	Amplitude ripple	882.4~912.6		0.9	2.0	dB	
	VSWR	ANT	882.4~912.6	-	1.5	2.0	-
		Tx		-	1.5	2.0	-
	Input Power	882.4~912.6	+29dBm Ta=+50℃ 5000h,CW			-	
			10~716	30	42	-	dB
			716~728	35	42	-	dB
			728~821	30	40	-	dB
			832~862	30	47	-	dB
			927.4~957.6	45	58	-	dB
			1559~1605	40	42	-	dB
			1710~1785	30	42	-	dB
			1760~1880	38	41	-	dB
			2110~2170	27	38	-	dB
			2400~2500	35	38	-	dB
		2620~2745	32	36	-	dB	
		3520~3660	20	35	-	dB	
		4400~4575	20	38	-	dB	
	4900~5950	15	20	-	dB		
ANT to RX	Insertion loss	927.4~957.6	-	2.0	3.2	dB	
	Pass band ripple	927.4~957.6		1.0	2.2	dB	
	VSWR	ANT	927.4~957.6	-	1.8	2.0	-
		Rx		-	1.8	2.0	-
	Absolute attenuation		10~880	45	60	-	dB
			882.4~912.6	45	60	-	dB
			1045~4625	40	48	-	dB
		4625~6000	30	35	-	dB	

Table2. Electrical Specification

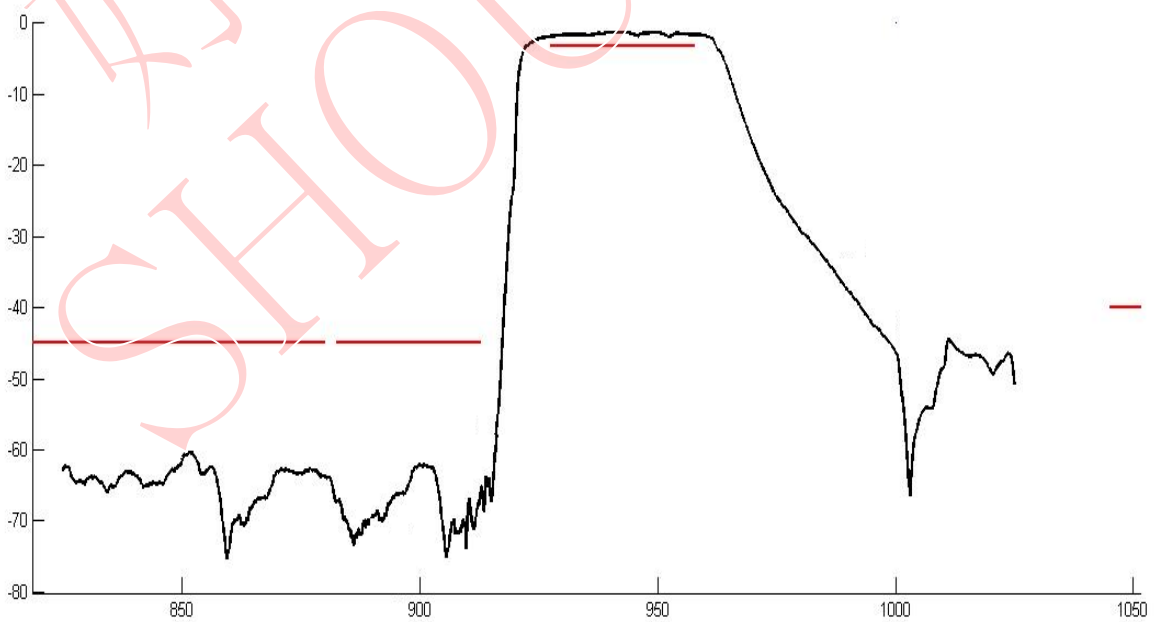
Item		Condition (MHz)	Specification			Unit
			Min	Typ	Max	
TX to RX	Isolation	882.4~912.6	55	57	-	dB
		927.4~957.6	55	60	-	dB
Terminating Impedance		Tx port	50Ω+2nH			
		Rx port	50Ω+4nH			
		Ant port	50Ω//6.8nH			
Operating Temperature			-30 to +85°C			

6. Typical frequency response

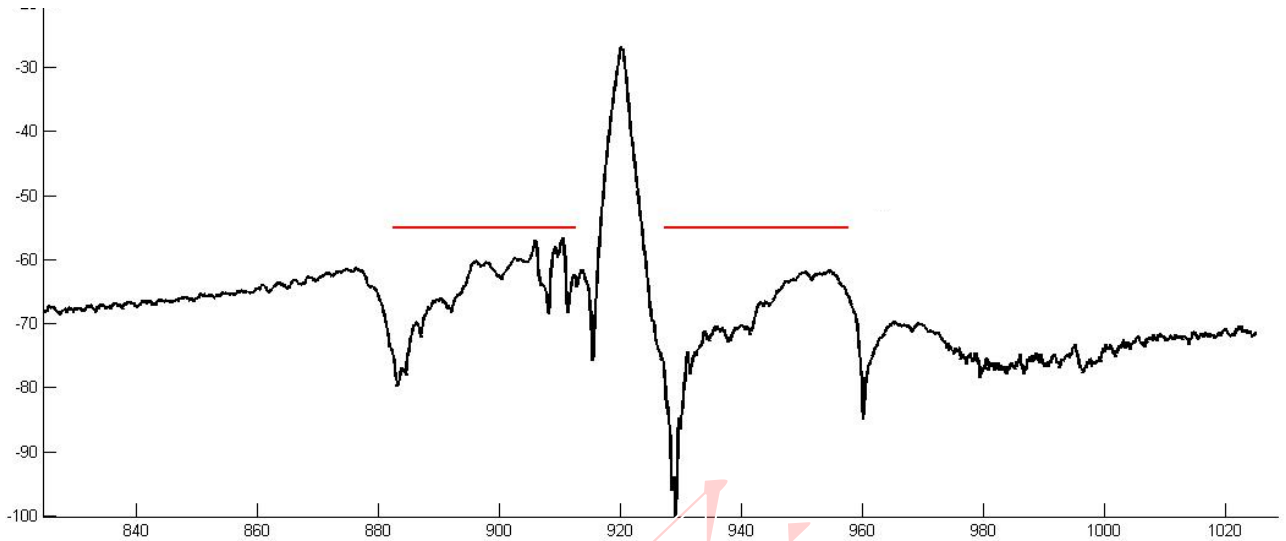
Tx to Ant



Ant to Rx



Tx to Rx Isolation



7. ENVIRONMENTAL CHARACTERISTICS

7.1 High temperature exposure

Subject the device to +85°C for 16 hours. Then release the filter into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 5.

7.2 Low temperature exposure

Subject the device to -40°C for 16 hours. Then release the device into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 5.

7.3 Temperature cycling

Subject the device to a low temperature of -40°C for 30 minutes. Following by a high temperature of +85°C for 30 Minutes. Then release the device into the room conditions for 24 hours prior to the measurement. It shall meet the specifications in 5.

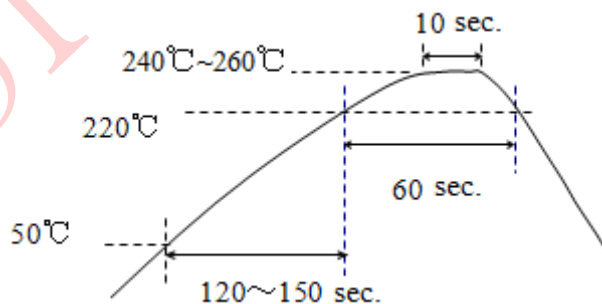
7.4 Resistance to solder heat

- 1、immerge the solder bath at 260°C for 10 sec.
- 2、 the iron at 370°C for 3 sec

7.5 Solderability

Submerge the device terminals into the solder bath at 245°C ±5°C for 5s, More than 95% area of the soldering pad must be covered with new solder. It shall meet the specifications in 5.

7.6 Reflow soldering



The specimen shall be passed through the reflow furnace with the condition shown in the above profile for 1 time.

The specimen shall be stored at standard atmospheric conditions for 1h, after which the measurement shall be made. Test board shall be 1.6 mm thick. Base material shall be glass fabric base epoxy resin.

7.7 Mechanical shock

Drop the device randomly onto the concrete floor from the height of 1m 3 times. the device shall fulfill the specifications in 5.

7.8 Vibration

Subject the device to the vibration for 1 hour each in x,y and z axes with the amplitude of 1.5 mm at 10 to 55 Hz. The device shall fulfill the specifications in 5.

8. REMARK

8.1 Static voltage

Static voltage between signal load & ground may cause deterioration & destruction of the component. Please avoid static voltage.

8.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning

8.3 Soldering

Only pad component may be soldered. Please avoid soldering another part of component.

9. Packing

9.1 Dimensions

(1) Carrier Tape: Figure 1

(2) Reel: Figure 2

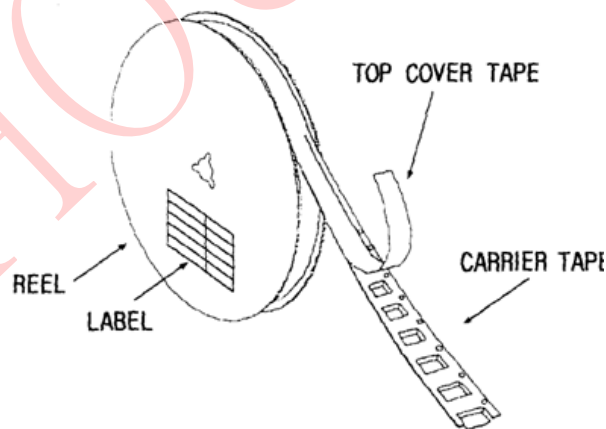
(3) The product shall be packed properly not to be damaged during transportation and storage.

9.2 Reeling Quantity

10000 pcs/reel ϕ 257.5mm

9.3 Taping Structure

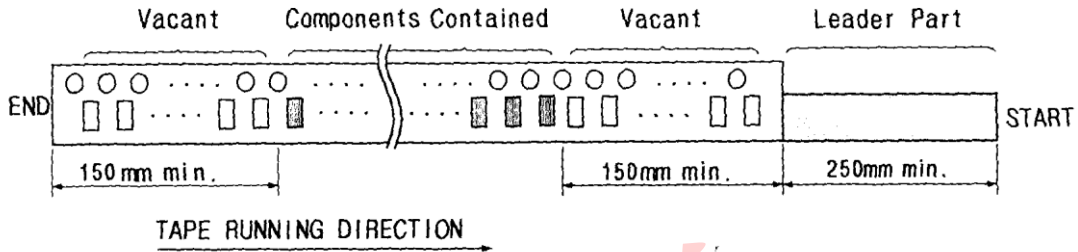
(1) The tape shall be wound around the reel in the direction shown below.



(2) Label

Device Name	
Marking	
User Product Name	
Quantity	
Lot No.	

(3) Leader part and vacant position specifications.

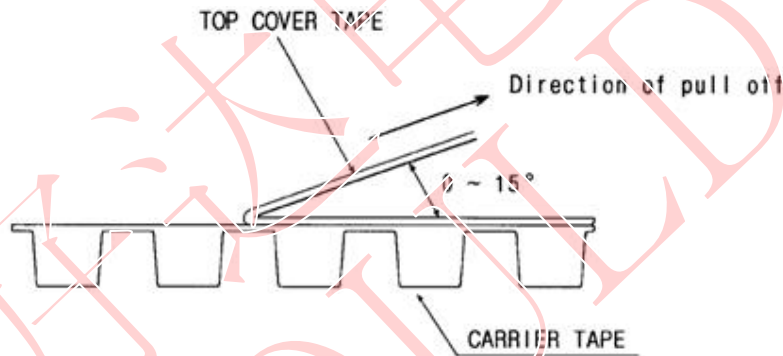


10. TAPE SPECIFICATIONS

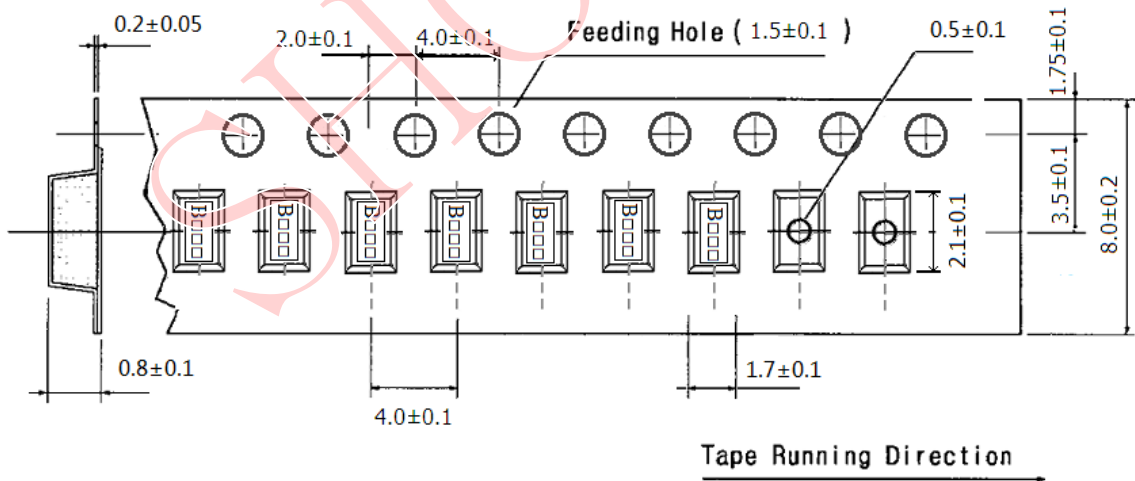
10.1 Tensile Strength of Carrier Tape: 4.4N/mm width

10.2 Top Cover Tape Adhesion (See the below figure)

- (1) pull off angle: 0~15°
- (2) speed: 300mm/min.
- (3) force: 20~70g



[Figure 1] Carrier Tape Dimensions



[Figure 2] 10000 pcs/reel ϕ 257.5mm

